

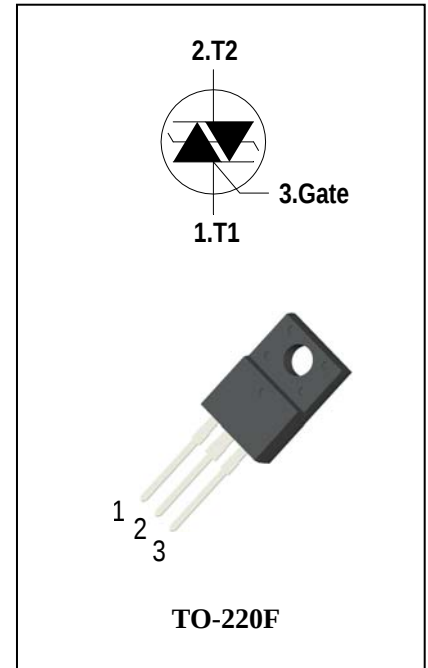
## AC Thyristor Triac power switch

### General Description

Available either in through-hole or surface-mount packages, the AACT12 suitable for general purpose AC switching. They can be used as an ON/OFF function in applications such as static relays, heating regulation, induction motor starting circuits... or for phase control operation in light dimmers, motor speed controllers,...

### Features

- ◆ Repetitive Peak Off-State Voltage: 800V and 1000V
- ◆ R.M.S On-State Current (  $I_{T(RMS)} = 12A$  )
- ◆ Very high immunity to false turn-on by  $dV/dt$
- ◆ Triggering in three quadrants only
- ◆ Pin compatible with standard triacs
- ◆ Safe clamping capability for low energy over-voltage transients
- ◆ These Devices are Pb-Free and are RoHS Compliant



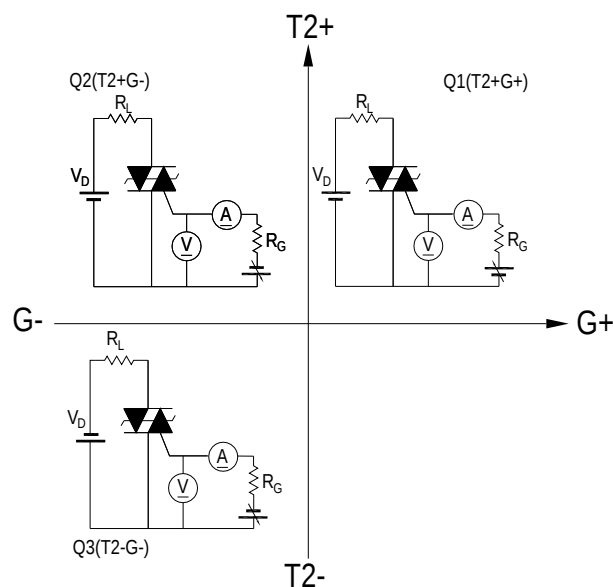
### Absolute Maximum Ratings

| Symbol                 | Items                                                          | Conditions                                                                                     |           | Ratings    | Unit        |
|------------------------|----------------------------------------------------------------|------------------------------------------------------------------------------------------------|-----------|------------|-------------|
| $V_{DRM}$<br>$V_{RRM}$ | Repetitive Peak Off-State Voltage                              | $T_j = 25^{\circ}C$                                                                            | AACT1208F | 800        | V           |
|                        |                                                                |                                                                                                | AACT1210F | 1000       | V           |
| $I_{T(RMS)}$           | R.M.S On-State Current                                         | $T_C = 92^{\circ}C$                                                                            |           | 12         | A           |
| $I_{TSM}$              | Surge On-State Current                                         | $t_p=20ms(50Hz)/t_p=16.7ms(60Hz)$                                                              |           | 120/126    | A           |
| $I^2t$                 | $I^2t$ for fusing                                              | $t_p=10ms$                                                                                     |           | 78         | $A^2s$      |
| $dI/dt$                | Critical rate of rise of on-state current                      | $F = 120\text{ Hz}$ $T_j = 125^{\circ}C$<br>$I_G = 2 \times I_{GT}$ , $t_r \leq 100\text{ ns}$ |           | 50         | $A/\mu s$   |
| $I_{GM}$               | Peak Gate Current                                              | $t_p = 20\text{ }\mu s$ $T_j = 125^{\circ}C$                                                   |           | 4          | A           |
| $P_{G(AV)}$            | Average Gate Power Dissipation( $T_j=125^{\circ}C$ )           |                                                                                                |           | 0.1        | W           |
| $P_{GM}$               | Peak Gate Power Dissipation( $t_p=20\mu s, T_j=125^{\circ}C$ ) |                                                                                                |           | 5          | W           |
| $T_j$                  | Operating Junction Temperature                                 |                                                                                                |           | - 40 ~ 125 | $^{\circ}C$ |
| $T_{STG}$              | Storage Temperature                                            |                                                                                                |           | - 40 ~ 150 | $^{\circ}C$ |

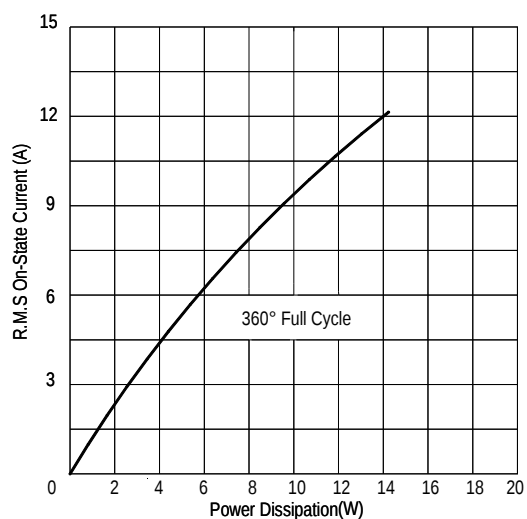


**Electrical Characteristics** (  $T_j = 25^\circ\text{C}$  unless otherwise specified )

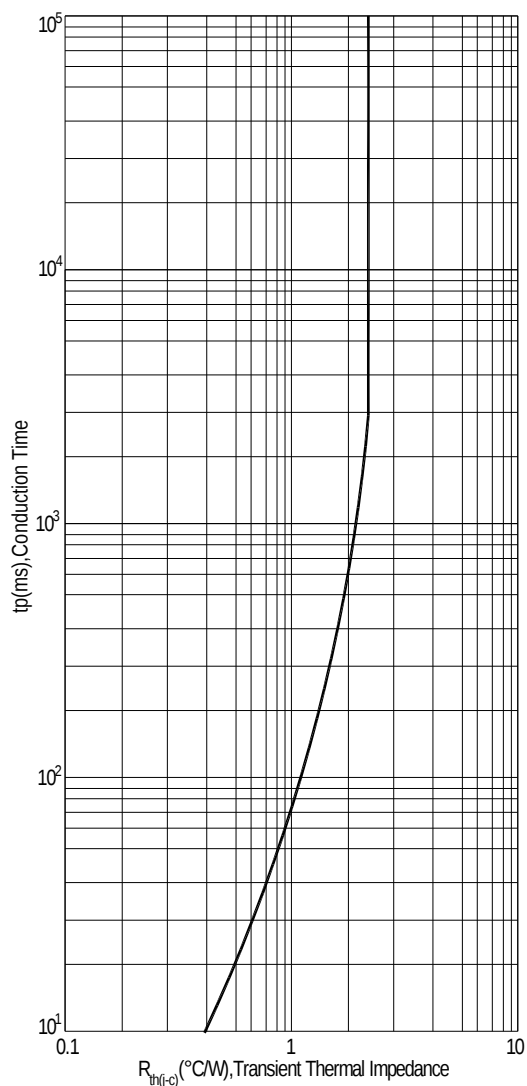
| Symbol                               | Items                                      |                          | Conditions                                                                                                          |      | AACT1208F/10F |       | Unit                 |
|--------------------------------------|--------------------------------------------|--------------------------|---------------------------------------------------------------------------------------------------------------------|------|---------------|-------|----------------------|
|                                      |                                            |                          |                                                                                                                     |      | S             | Blank |                      |
| $I_{\text{DRM}}$<br>$I_{\text{RRM}}$ | Peak Forward Reverse Blocking Current      |                          | $V_{\text{DRM}} = V_{\text{RRM}}, T_{\text{j}} = 25^{\circ}\text{C}$                                                | Max. | 5             |       | $\mu\text{A}$        |
|                                      |                                            |                          | $V_{\text{DRM}} = V_{\text{RRM}}, T_{\text{j}} = 125^{\circ}\text{C}$                                               |      | 1             |       | mA                   |
| $V_{\text{TM}}$                      | Peak On-State Voltage                      |                          | $I_{\text{TM}} = 17\text{A}, t_{\text{p}} = 380\text{ }\mu\text{s}$                                                 | Max. | 1.65          |       | V                    |
| $V_{\text{GD}}$                      | Q1-Q2-Q3                                   | Non–Trigger Gate Voltage | $V_{\text{D}} = 2/3V_{\text{DRM}}\text{ }R_{\text{L}} = 3.3\text{ k}\Omega$<br>$T_{\text{j}} = 125^{\circ}\text{C}$ | 0.2  | 0.2           |       | V                    |
| $V_{\text{GT}}$                      | Q1-Q2-Q3                                   | Gate Trigger Voltage     | $V_{\text{D}} = 12\text{V}\text{ }, R_{\text{L}} = 33\Omega$                                                        | 1.5  | 1.5           |       | V                    |
| $I_{\text{GT}}$                      | Q1-Q2-Q3                                   | Gate Trigger Current     |                                                                                                                     | 10   | 10            | 35    | mA                   |
| $I_{\text{H}}$                       | Q1-Q2-Q3                                   | Holding Current          | $I_{\text{T}} = 0.1\text{A}$                                                                                        | 15   | 15            | 45    | mA                   |
| $I_{\text{L}}$                       | Q1-Q3                                      | Latching Current         | $I_{\text{G}} = 1.2\text{ }I_{\text{GT}}$                                                                           | 20   | 20            | 50    | mA                   |
|                                      | Q2                                         |                          |                                                                                                                     | 30   | 30            | 70    |                      |
| dV/dt                                | Critical Rate of Rise of Off-State Voltage |                          | $V_{\text{D}} = 2/3V_{\text{DRM}}\text{ }\text{gate open}$<br>$T_{\text{j}} = 125^{\circ}\text{C}$                  | Min. | 1000          | 1500  | V/ $\mu\text{s}$     |
| $R_{\text{th(j-c)}}$                 | Junction to case (AC)                      |                          |                                                                                                                     | Max. | 2.3           |       | $^{\circ}\text{C/W}$ |
| $R_{\text{th(j-a)}}$                 | Junction to ambient                        |                          |                                                                                                                     | Max. | 60            |       | $^{\circ}\text{C/W}$ |

**FIG.1: Quadrant are defined and the gate trigger test circuit**

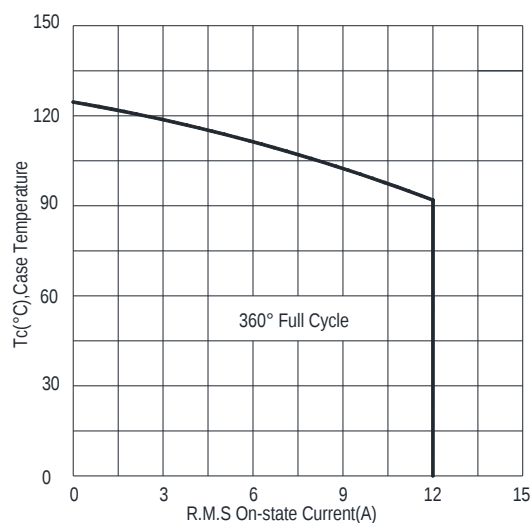
**FIG.2: Maximum on-state power dissipation**



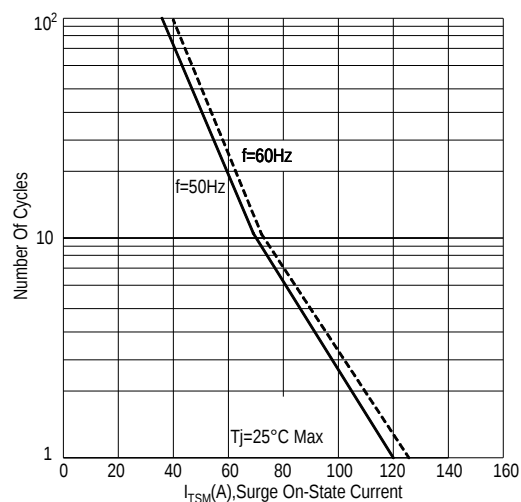
**FIG.4: Maximum transient thermal impedance**



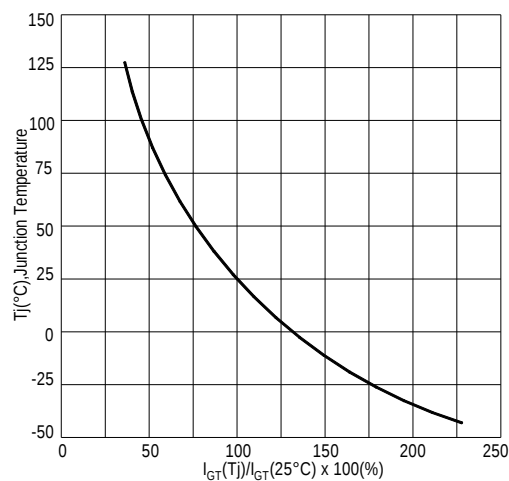
**FIG.3: Typical RMS on-state current VS Allowable case Temperature**



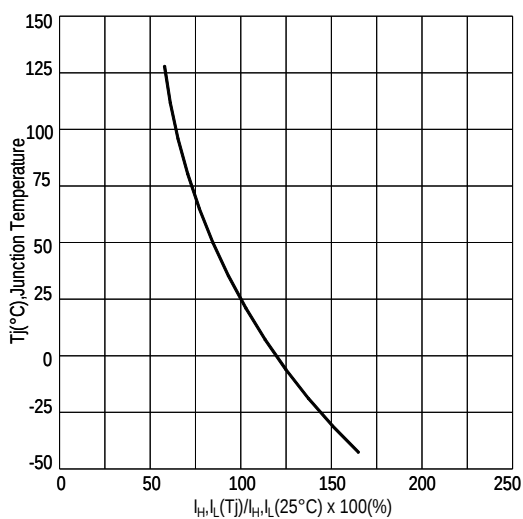
**FIG.5: Rated surge on-state current ( Non-Repetitive)**



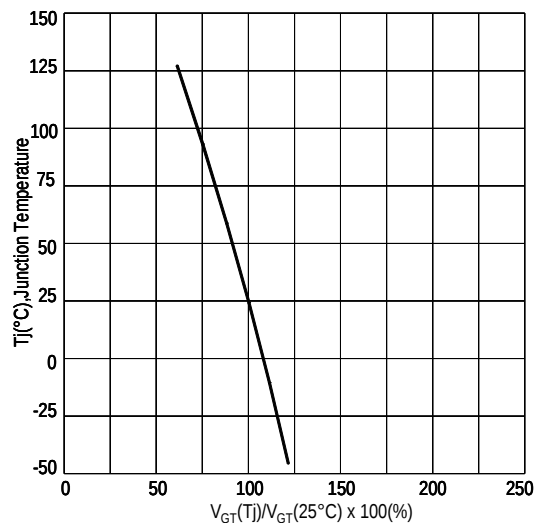
**FIG.6: Gate trigger current VS Junction temperature**



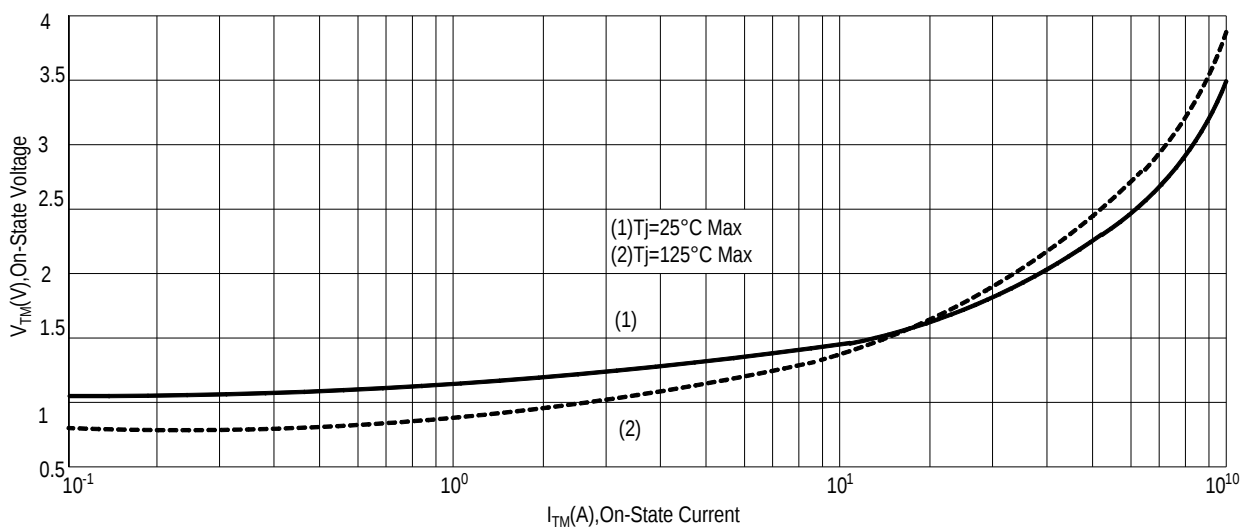
**FIG.7: Holding current and Latching current VS Junction temperature**



**FIG.8: Gate trigger voltage VS Junction temperature**

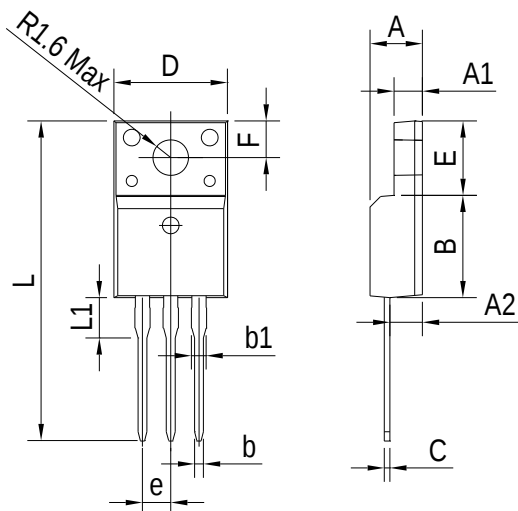


**FIG.9: On-state characteristics(Max)**



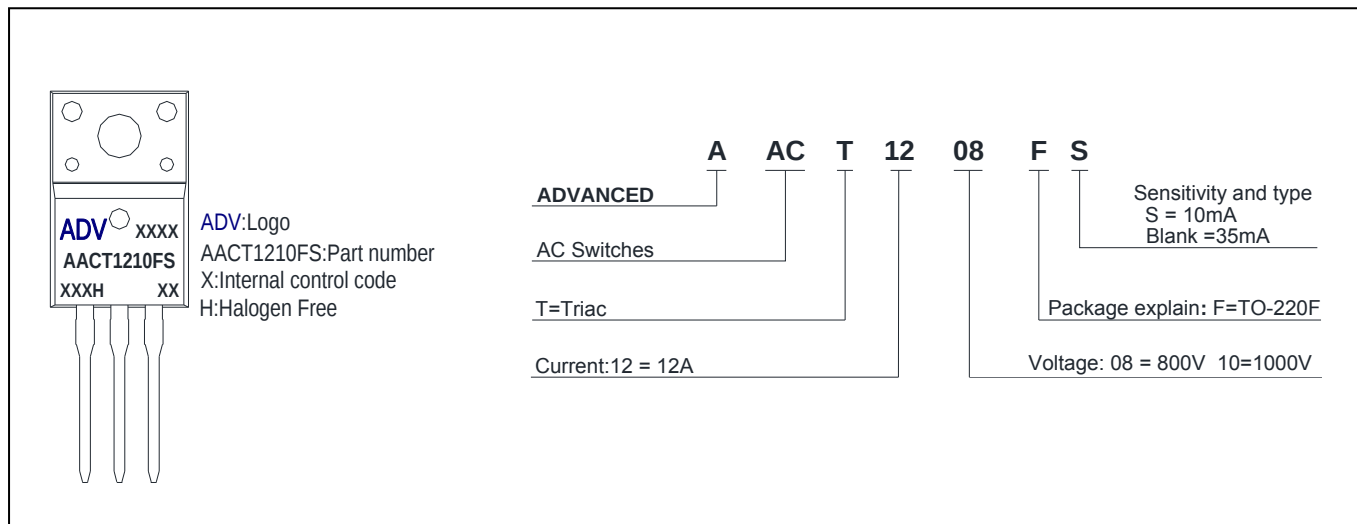
## PACKAGE MECHANICAL DATA

### TO-220F Package Dimension



| Symbol | Dimensions In Millimeters |        | Dimensions In Inches |       |
|--------|---------------------------|--------|----------------------|-------|
|        | Min                       | Max    | Min                  | Max   |
| A      | 4.300                     | 4.800  | 0.169                | 0.189 |
| A1     | 2.400                     | 2.700  | 0.094                | 0.106 |
| A2     | 2.500                     | 3.000  | 0.098                | 0.118 |
| B      | 8.800                     | 9.300  | 0.346                | 0.367 |
| b      | 0.600                     | 0.950  | 0.023                | 0.037 |
| b1     | 1.100                     | 1.700  | 0.043                | 0.067 |
| C      | 0.500                     | 0.750  | 0.020                | 0.030 |
| D      | 9.700                     | 10.360 | 0.382                | 0.408 |
| E      | 6.400                     | 6.800  | 0.252                | 0.268 |
| e      | 2.540 TYP                 |        | 0.100 TYP            |       |
| F      | 3.300 REF                 |        | 0.130 REF            |       |
| L      | 28.000                    | 30.000 | 1.102                | 1.181 |
| L1     | 2.900                     | 3.630  | 0.114                | 0.143 |

## Making Diagram



## Ordering information

| Part number | Package | Marking    | Packing | Quantity |
|-------------|---------|------------|---------|----------|
| AACT1208F#  | TO-220F | AACT1208F# | Tube    | 50pcs    |
| AACT1210F#  | TO-220F | AACT1210F# | Tube    | 50pcs    |

Note:# = Gate Trigger Current Sensitivity and type

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